TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74ACT151P, TC74ACT151F, TC74ACT151FN

8-CHANNEL MULTIPLEXER

The TC74ACT151 is an advanced high speed CMOS 8 CHANNEL MULTIPLEXER fabricated with silicon gate and double - layer metal wiring C2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

One of eight date input signals (D0 - D7) is selected by decoding of the three - bit address input (A, B, C). The selected data appears on two outputs: non-inverting (Y) and inverting (W).

The $\overline{\text{STROBE}}$ input provides two output conditions; a low level on the STROBE input transferrs the selected data to the outputs. A high level on the STROBE input sets the Y output low and the the W output high without regard to the data or select input conditions.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

FEATURES:

- High Speed-----t_{pd} = 7.1ns(typ.) at V_{CC} = 5V
- Compatible with TTL outputs $\cdots V_{1L} = 0.8V$ (Max.)

 $V_{IH} = 2.0V (Min.)$

• Symmetrical Output Impedance | I_{OH} | = I_{OL} = 24mA(Min.)

Capability of driving 50Ω transmission lines.

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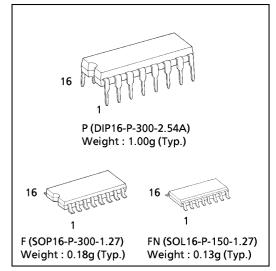
- Balanced Propagation Delays $\cdots t_{pLH} \simeq t_{pHL}$
- Pin and Function Compatible with 74F151

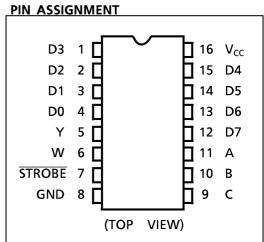
TRUTH TABLE

	IN	PUT	OUTPUT			
S	ELECT			\ \	۱۸/	
С	В	Α	STROBE	Ť	W	
Х	Х	Χ	Н	L	Н	
L	L	L	L	D0	D0	
L	L	Н	L	D1	$\overline{D}1$	
L	н	L	L	D2	D ₂	
L	Н	Н	L	D3	D ₃	
Н	L	L	L	D4	D4	
Н	L	Н	L	D5	D̄5	
Н	Н	L	L	D6	D 6	
Н	Н	Н	L	D7	D7	

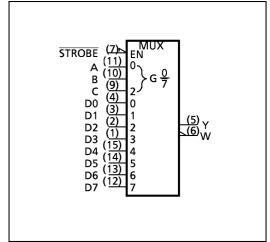
X: Don't Care

(Note) The JEDEC SOP (FN) is not available in Japan.

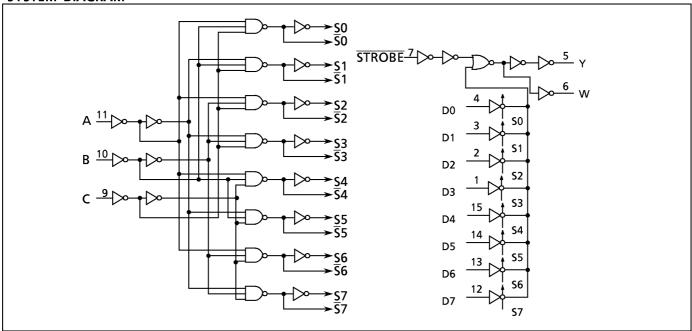




IEC LOGIC SYMBOL







ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{cc}	-0.5~7.0	٧
DC Input Voltage	VIN	$-0.5 \sim V_{CC} + 0.5$	٧
DC Output Voltage	V _{OUT}	$-0.5 \sim V_{CC} + 0.5$	V
Input Diode Current	I _{IK}	± 20	mA
Output Diode Current	I _{OK}	± 50	mA
DC Output Current	I _{OUT}	± 50	mA
DC V _{CC} /Ground Current	I _{cc}	± 100	mA
Power Dissipation	P _D	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	T _{stg}	−65~150	°C

*500mW in the range of Ta = -40°C~65°C. From Ta = 65°C to 85°C a derating factor of -10mW/°C should be applied up to 300mW.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V _{CC}	4.5~5.5	V
Input Voltage	VIN	0~V _{cc}	V
Output Voltage	V _{OUT}	0~V _{cc}	V
Operating Temperature	T _{opr}	−40~85	°C
Input Rise and Fall Time	dt/dV	0~10	ns / V

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION		V _{CC}	Ta = 25°C			Ta = −40~85°C		UNIT
PARAIVIETER	STIVIBUL			(>)	MIN.	TYP.	MAX.	MIN.	MAX.	UIVIII
High - Level Input Voltage	V _{IH}			4.5 \$ 5.5	2.0	_	_	2.0	_	٧
Low - Level Input Voltage	VIL			4.5 \$ 5.5	_	-	0.8	_	0.8	٧
High - Level Output Voltage	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -50 \mu A$ $I_{OH} = -24 m A$ $I_{OH} = -75 m A *$	4.5 4.5 5.5	4.4 3.94 —	4.5 - -		4.4 3.80 3.85	_ _ _	٧
Low - Level Output Voltage	V _{OL}	V _{IN} =	$I_{OL} = 50 \mu A$ $I_{OL} = 24 m A$ $I_{OL} = 75 m A *$	4.5 4.5 5.5	111	0.0 _ _	0.1 0.36 —	1 1 1	0.1 0.44 1.65	V
Input Leakage Current	I _{I N}	$V_{IN} = V_{CC}$ or GND		5.5	_	1	± 0.1	_	± 1.0	μΑ
Quiescent Supply Current	I _{cc}	$V_{IN} = V_{CC}$ or GND		5.5	_		8.0	_	80.0	μ
	I _C	PER INPUT : V _{II} OTHER INPUT	5.5	_	_	1.35	_	1.5	mA	

^{* :} This spec indicates the capability of driving 50Ω transmission lines. One output should be tested at a time for a 10ms maximum duration.

AC ELECTRICAL CHARACTERISTICS (C_L = 50pF , R_L = 500 Ω , input t_r = t_f = 3ns)

PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C			$Ta = -40 \sim 85^{\circ}C$		UNIT
FARAIVIETER	STIVIBOL		V _{cc} (V)	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT
Propagation Delay Time (D-Y,W)	t _{pLH} t _{pHL}		5.0 ± 0.5	_	7.5	11.8	1.0	13.5	
Propagation Delay Time (A,B,C-Y,W)	t _{pLH} t _{pHL}		5.0 ± 0.5	_	9.5	15.8	1.0	18.0	ns
Propagation Delay Time (ST-Y,W)	t _{pLH} t _{pHL}		5.0 ± 0.5	_	6.3	10.1	1.0	11.5	
Input Capacitance	C _{IN}			_	5	10	_	10	pF
Power Dissipation Capacitance	C _{PD} (1)			_	66	_	_	_] "

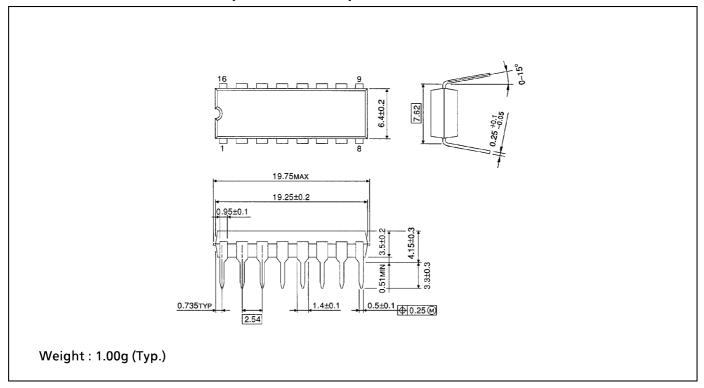
Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC}(opr.) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

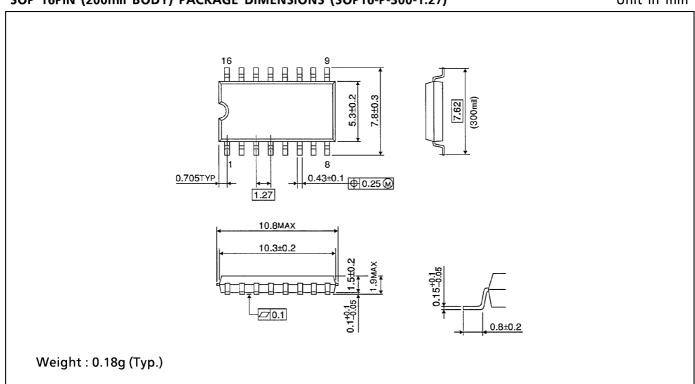
DIP 16PIN PACKAGE DIMENSIONS (DIP16-P-300-2.54A)

Unit in mm



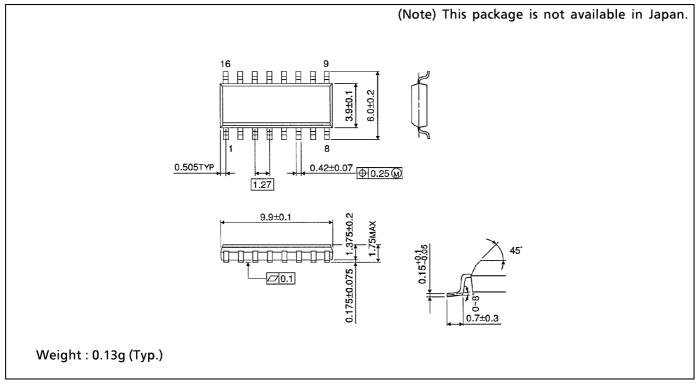
SOP 16PIN (200mil BODY) PACKAGE DIMENSIONS (SOP16-P-300-1.27)

Unit in mm



SOP 16PIN (150mil BODY) PACKAGE DIMENSIONS (SOL16-P-150 -1.27)

Unit in mm



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